

COMPLEMENTARY SILICON PLASTIC POWER TRANSISTORS

... designed for use in general purpose power amplifier and switching applications.

FEATURES:

- * Collector-Emitter Sustaining Voltage -

$V_{CEO(sus)} = 45V(\text{Min})$ - BD243,BD244

60V(Min)- BD243A,BD244A

80V(Min)- BD243B,BD244B

100V(Min)- BD243C,BD244C

- * DC Current Gain $h_{FE} = 30(\text{Min}) @ I_C = 0.3A$

- * Current Gain-Bandwidth Product $f_T = 3.0 \text{ MHz}(\text{Min}) @ I_C = 500mA$

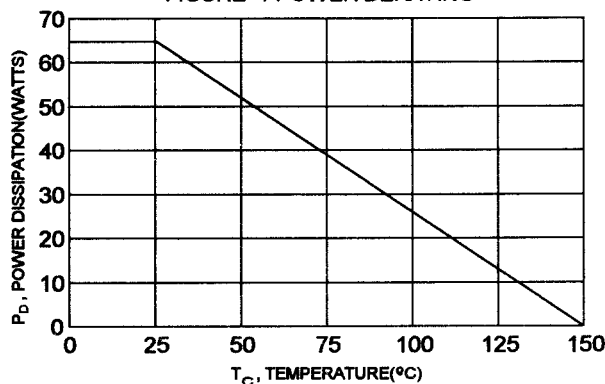
MAXIMUM RATINGS

Characteristic	Symbol	BD243 BD244	BD243A BD244A	BD243B BD244B	BD243C BD244C	Unit
Collector-Emitter Voltage	V_{CEO}	45	60	80	100	V
Collector-Base Voltage	V_{CBO}	45	60	80	100	V
Emitter-Base Voltage	V_{EBO}	5.0				V
Collector Current - Continuous - Peak	I_C	6.0 10				A
Base Current	I_B	2.0				A
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	65 0.52				W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-65 to +150				$^\circ\text{C}$

THERMAL CHARACTERISTICS

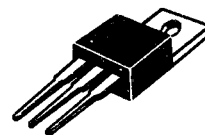
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	$R_{\theta jc}$	1.92	$^\circ\text{C/W}$

FIGURE -1 POWER DERATING

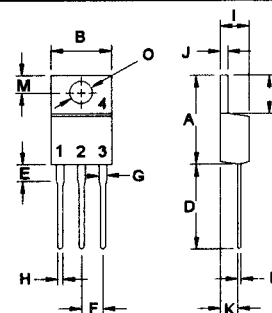


NPN	PNP
BD243	BD244
BD243A	BD244A
BD243B	BD244B
BD243C	BD244C

6 AMPERE
COMPLEMENTARY SILICON
POWER TRANSISTORS
45 -100 VOLTS
65 WATTS



TO-220



PIN 1.BASE
2.COLLECTOR
3.EMITTER
4.COLLECTOR(CASE)

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.31
B	9.78	10.42
C	5.01	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	3.66
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.97
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage(1) ($I_C = 30\text{ mA}$, $I_B = 0$)	BD243,BD244 BD243A,BD244A BD243B,BD244B BD243C,BD244C	$V_{CE(sus)}$	45 60 80 100	V
Collector Cutoff Current ($V_{CE} = 30\text{ V}$, $I_B = 0$) ($V_{CE} = 60\text{ V}$, $I_B = 0$)	BD243/44/43A/44A BD243B/44B/43C/44C	I_{CEO}	0.7 0.7	mA
Collector Cutoff Current ($V_{CE} = 45\text{ V}$, $V_{EB} = 0$) ($V_{CE} = 60\text{ V}$, $V_{EB} = 0$) ($V_{CE} = 80\text{ V}$, $V_{EB} = 0$) ($V_{CE} = 100\text{ V}$, $V_{EB} = 0$)	BD243/44 BD243A/44A BD243B/44B BD243C/44C	I_{CES}	0.4 0.4 0.4 0.4	mA
Emitter Cutoff Current ($V_{EB} = 5.0\text{ V}$, $I_C = 0$)		I_{EBO}	1.0	mA

ON CHARACTERISTICS (1)

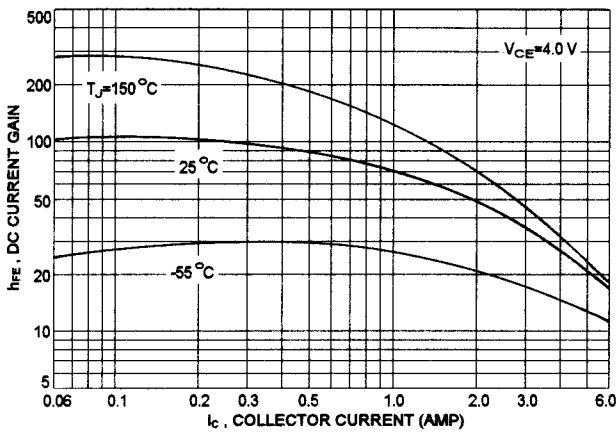
DC Current Gain ($V_{CE} = 4.0\text{ V}$, $I_C = 0.3\text{ A}$) ($V_{CE} = 4.0\text{ V}$, $I_C = 3.0\text{ A}$)	h_{FE}	30 15		
Collector-Emitter Saturation Voltage ($I_C = 6.0\text{ A}$, $I_B = 1.0\text{ A}$)	$V_{CE(sat)}$		1.5	V
Base-Emitter On Voltage ($I_C = 6.0\text{ A}$, $V_{CE} = 4.0\text{ V}$)	$V_{BE(on)}$		2.0	V

DYNAMIC CHARACTERISTICS

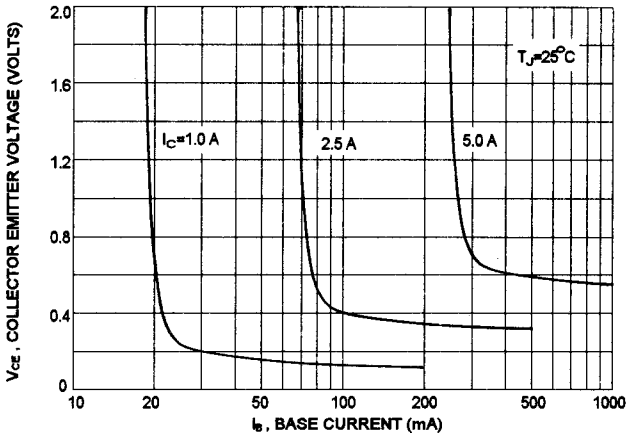
Current Gain-Bandwidth Product (2) ($I_C = 500\text{ mA}$, $V_{CE} = 10\text{ V}$, $f = 1\text{ MHz}$)	f_T	3.0		MHz
Small-Signal Current Gain ($I_C = 500\text{ mA}$, $V_{CE} = 10\text{ V}$, $f = 1\text{ KHz}$)	h_{fe}	20		

(1) Pulse Test: Pulse width = $300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$ (2) $f_T = |h_{fe}| \cdot f_{test}$

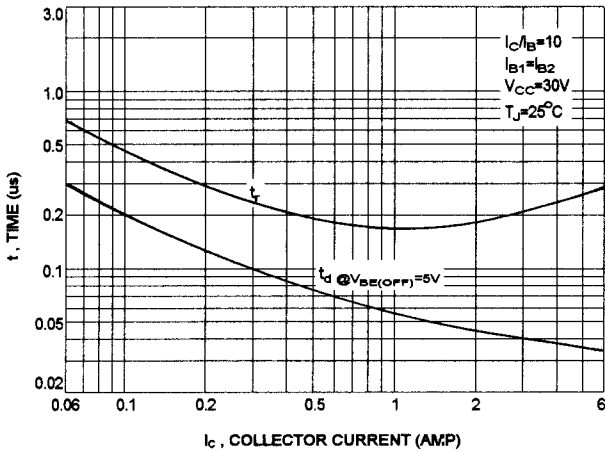
DC CURRENT GAIN



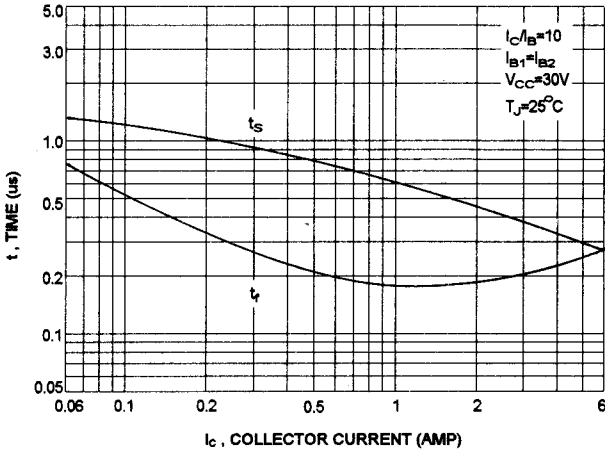
COLLECTOR SATURATION REGION



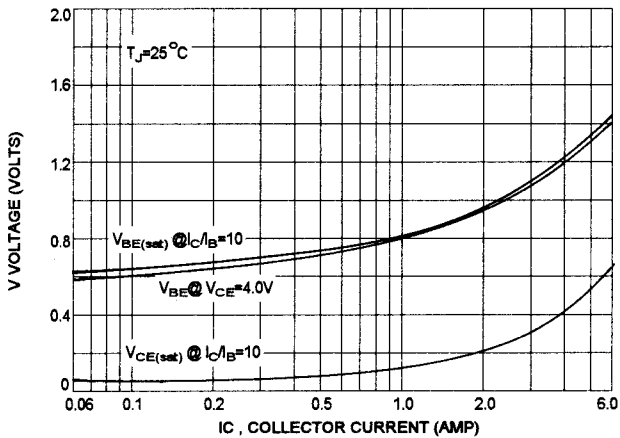
TURN-ON TIME



TURN-OFF TIME



"ON" VOLTAGES



ACTIVE REGION SAFE OPERATING AREA

